High-frequency Press-pack SiC Modules for Future Resilient Energy Infrastructure

Presenter: **Jun Wang**, Assistant Professor, University of Nebraska-Lincoln Sandia Power Electronics & Energy Conversion Workshop, Albuquerque, NM, July 31, 2024.

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The U.S. Needs a More Powerful Grid



Al infrastructure: Power-hungry data centers



Much more electricity must be delivered to these loads via a more POWERFUL grid (!)



Need for More Advanced Power Electronics

Power electronics is key to providing a more POWERFUL and SUSTAINABLE grid (!)



Existing Device Packages are a Bottleneck



Module property	Conduction loss	Switching loss	Switch. freq./ control BW	Parasitics	Thermal conductivity	Explosion- proof	Integrated gate driver
SoA-1: Si IGBT, IGCT, and SCR	Low	High	Low	High	High	Yes	Partly
SoA-2: SiC FET	High	Low	High	Low	Low	No	No
Proposed SiC FET MetaPak	Low	Low	High	Low	High	Yes	Yes



Proposed MetaPak: New Topology + Package + Intelligence



Innovation 1: Switch-cell building block (SCBB) architecture with high flexibility and minimized power-loop inductance (< 10 nH). (Patented)</p>



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Innovation 3: MetaMind device manager and E-field and EMI containment. (Patented)







Prospective Impact to Grid Infrastructure

- Enable new HV converter topologies and paradigm-shifting converter designs.
- Unleash the untapped potential of HV SiC MOSFETs.





1.2 kV Proof-of-Concept Prototype



BeCu MS compression test (896 N/1.06 mm)





UNL-PESL Facilities (2,500 sq. ft) and Equipment



AJA ATC-2000F









AMX P52



Nordson DAGE 4000 Plus

Tresky T-5300



TPT HB30

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Thank you!





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